

2N5684 (PNP), 2N5686 (NPN)

High-Current Complementary Silicon Power Transistors

These packages are designed for use in high-power amplifier and switching circuit applications.

Features

- High Current Capability - I_C Continuous = 50 Amperes
- DC Current Gain - $h_{FE} = 15 - 60 @ I_C = 25 \text{ Adc}$
- Low Collector-Emitter Saturation Voltage -
 $V_{CE(sat)} = 1.0 \text{ Vdc (Max) @ } I_C = 25 \text{ Adc}$
- Pb-Free Packages are Available*

MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	80	Vdc
Collector-Base Voltage	V_{CB}	80	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current - Continuous	I_C	50	Adc
Base Current	I_B	15	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	300 1.715	mW mW/ $^\circ\text{C}$
Operating and Storage Temperature Range	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	θ_{JC}	0.584	$^\circ\text{C/W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates JEDEC Registered Data.

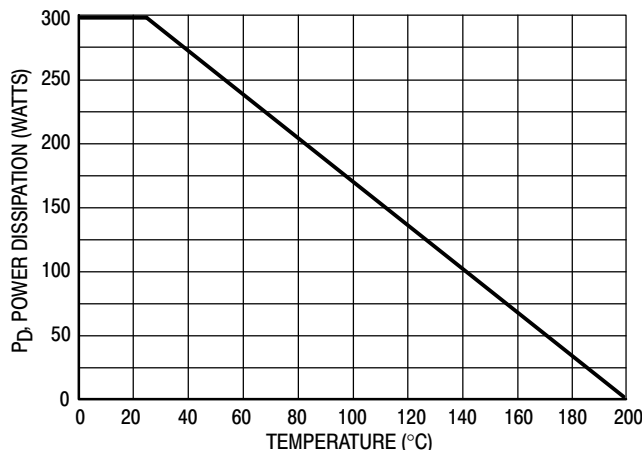


Figure 1. Power Derating

Safe Area Curves are indicated by Figure 5. All limits are applicable and must be observed.

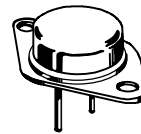


ON Semiconductor®

<http://onsemi.com>

50 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 60-80 VOLTS, 300 WATTS

MARKING DIAGRAM



TO-204 (TO-3)
CASE 197A
STYLE 1

- 2N568x = Device Code
x = 4 or 6
G = Pb-Free Package
A = Location Code
YY = Year
WW = Work Week
MEX = Country of Origin

ORDERING INFORMATION

Device	Package	Shipping
2N5684G	TO-3 (Pb-Free)	100 Units/Tray
2N5686	TO-3	100 Units/Tray
2N5686G	TO-3 (Pb-Free)	100 Units/Tray

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted) (Note 2)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage (Note 3)	$(I_C = 0.2 \text{ Adc}, I_B = 0)$	$V_{CEO(sus)}$	80	-	Vdc
Collector Cutoff Current	$(V_{CE} = 40 \text{ Vdc}, I_B = 0)$	I_{CEO}	-	1.0	mAdc
Collector Cutoff Current	$(V_{CE} = 80 \text{ Vdc}, V_{EB(off)} = 1.5 \text{ Vdc})$ $(V_{CE} = 80 \text{ Vdc}, V_{EB(off)} = 1.5 \text{ Vdc}, T_C = 150^\circ\text{C})$	I_{CEX}	-	2.0	mAdc
Collector Cutoff Current	$(V_{CB} = 80 \text{ Vdc}, I_E = 0)$	I_{CBO}	-	2.0	mAdc
Emitter Cutoff Current	$(V_{BE} = 5.0 \text{ Vdc}, I_C = 0)$	I_{EBO}	-	5.0	mAdc

ON CHARACTERISTICS

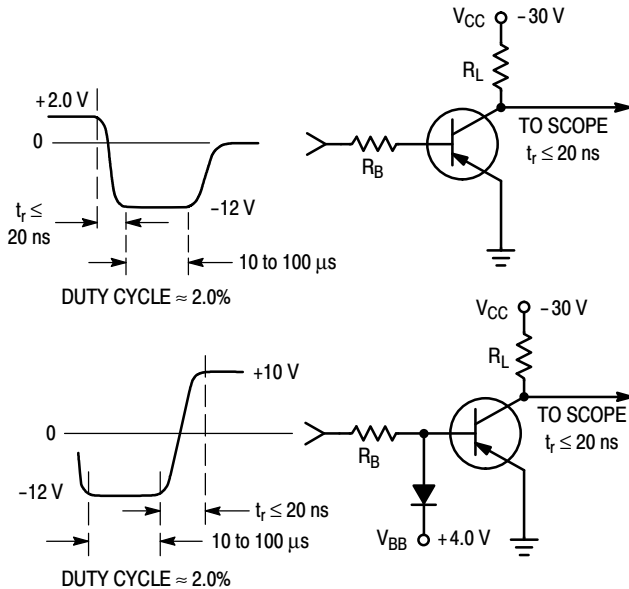
DC Current Gain (Note 3)	$(I_C = 25 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc})$ $(I_C = 50 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc})$	h_{FE}	15 5.0	60 -	-
Collector-Emitter Saturation Voltage (Note 3)	$(I_C = 25 \text{ Adc}, I_B = 2.5 \text{ Adc})$ $(I_C = 50 \text{ Adc}, I_B = 10 \text{ Adc})$	$V_{CE(sat)}$	-	1.0 5.0	Vdc
Base-Emitter Saturation Voltage (Note 2)	$(I_C = 25 \text{ Adc}, I_B = 2.5 \text{ Adc})$	$V_{BE(sat)}$	-	2.0	Vdc
Base-Emitter On Voltage (Note 2)	$(I_C = 25 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc})$	$V_{BE(on)}$	-	2.0	Vdc

DYNAMIC CHARACTERISTICS

Current-Gain - Bandwidth Product	$(I_C = 5.0 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ MHz})$	f_T	2.0	-	MHz
Output Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 0.1 \text{ MHz})$	2N5684 2N5686	C_{ob}	-	2000 1200	pF
Small-Signal Current Gain	$(I_C = 10 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}, f = 1.0 \text{ kHz})$	h_{fe}	15	-	

2. Indicates JEDEC Registered Data.

3. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.



FOR CURVES OF FIGURES 3 & 6, R_B & R_L ARE VARIED.
INPUT LEVELS ARE APPROXIMATELY AS SHOWN.
FOR NPN CIRCUITS, REVERSE ALL POLARITIES.

Figure 2. Switching Time Test Circuit

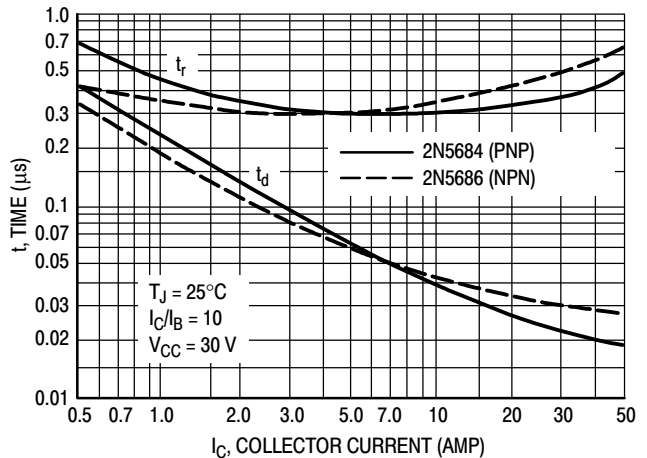


Figure 3. Turn-On Time

2N5684 (PNP), 2N5686 (NPN)

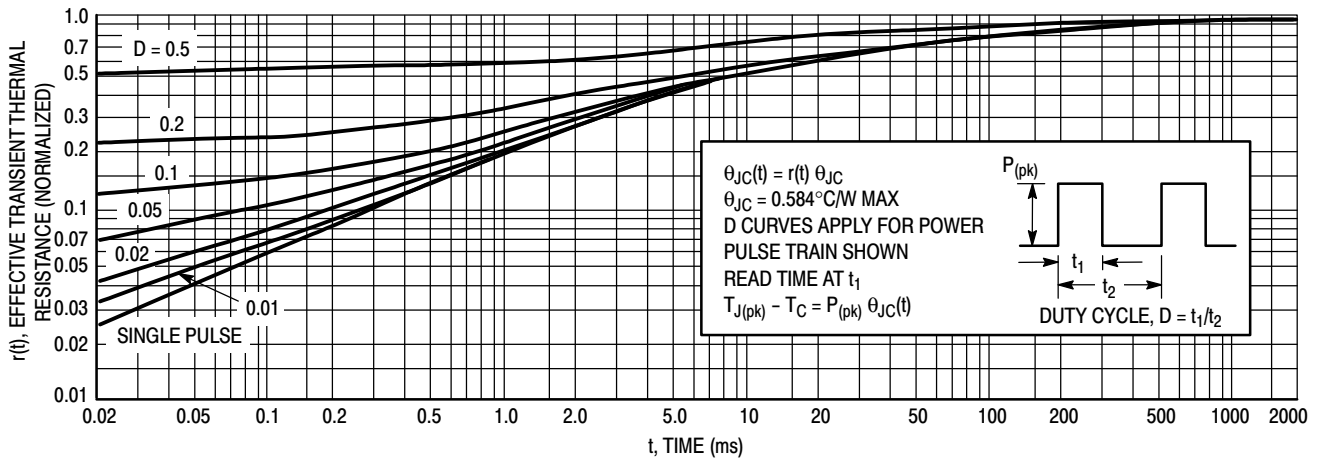


Figure 4. Thermal Response

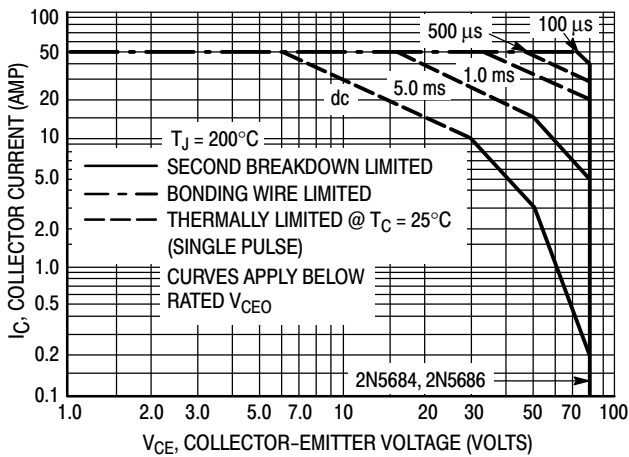


Figure 5. Active-Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 200^{\circ}\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 200^{\circ}\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

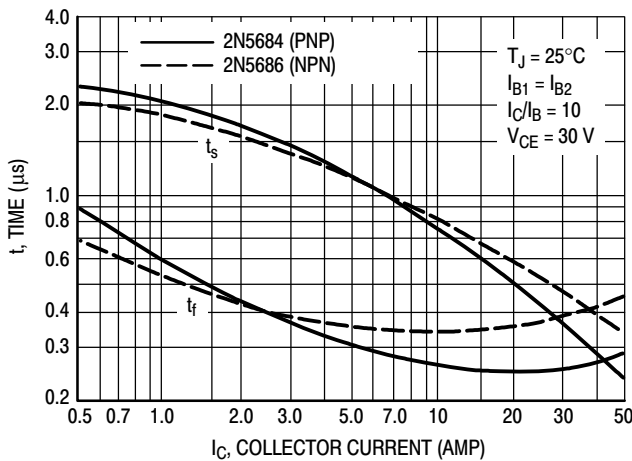


Figure 6. Turn-Off Time

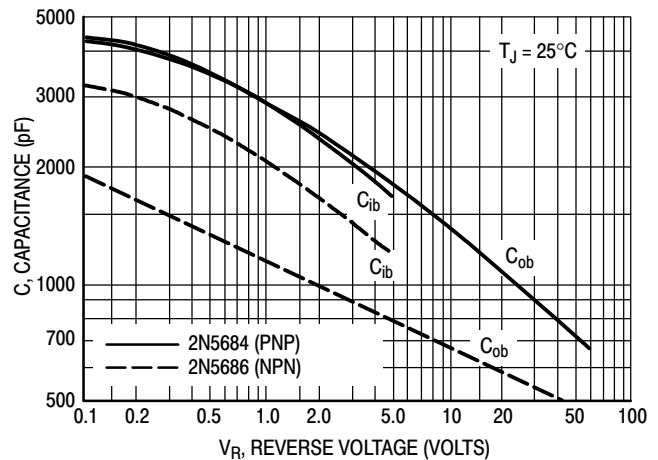


Figure 7. Capacitance

2N5684 (PNP), 2N5686 (NPN)

PNP
2N5684

NPN
2N5686

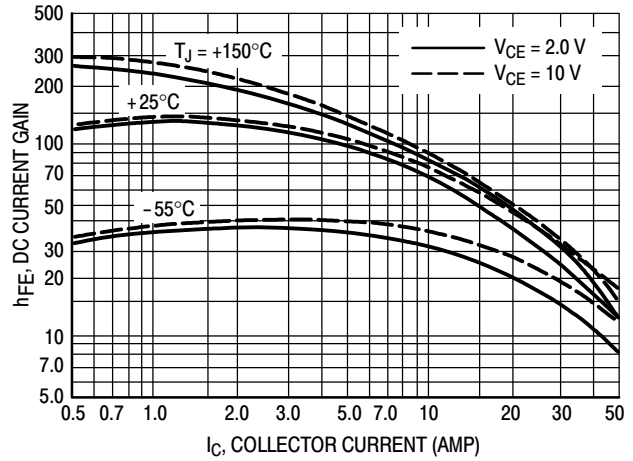
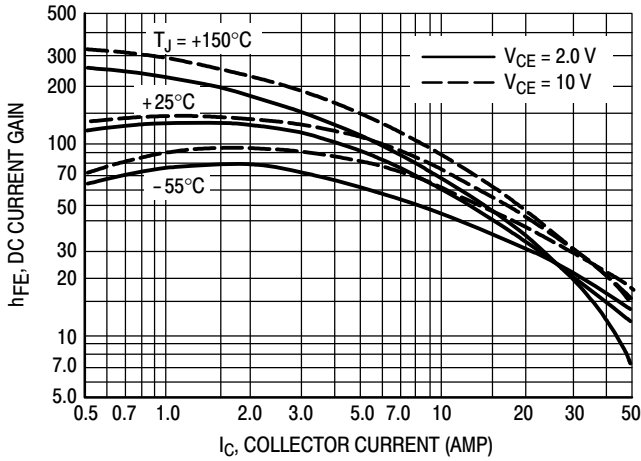


Figure 8. DC Current Gain

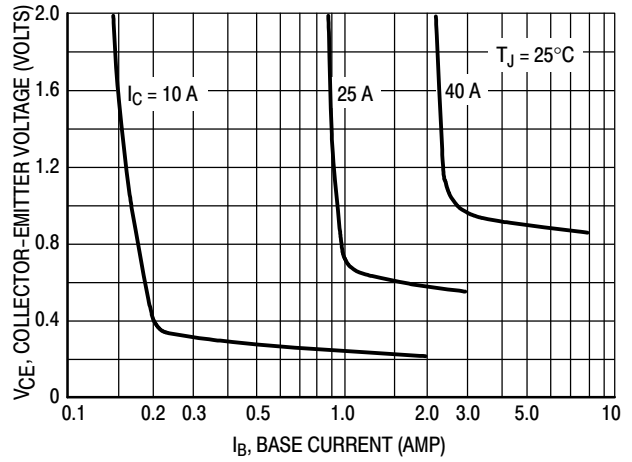
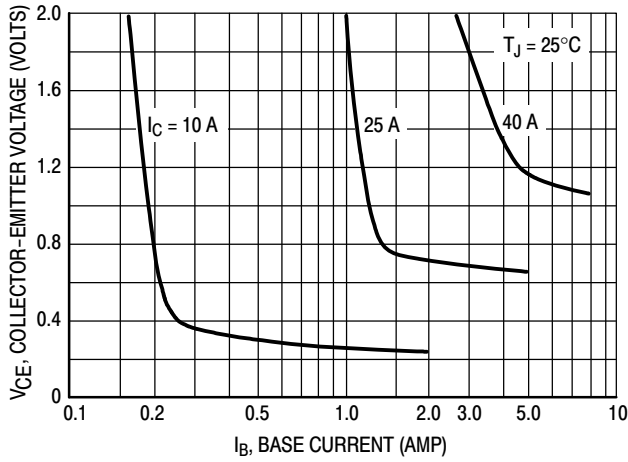


Figure 9. Collector Saturation Region

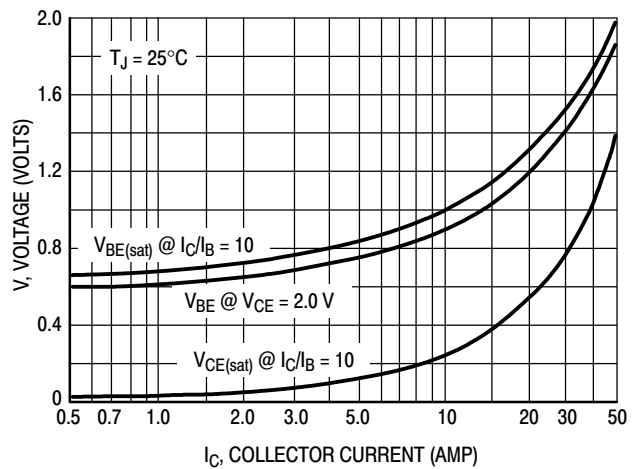
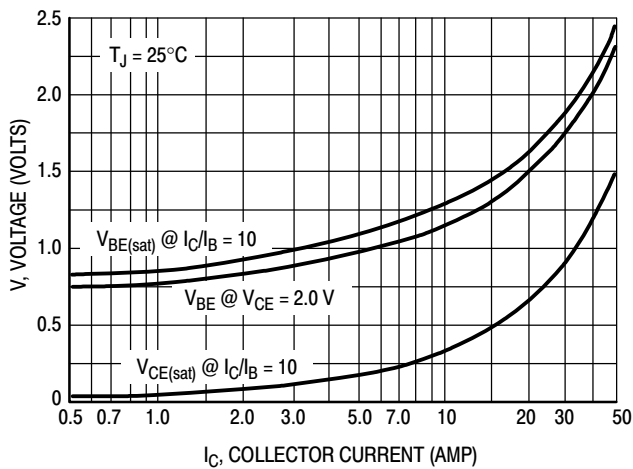
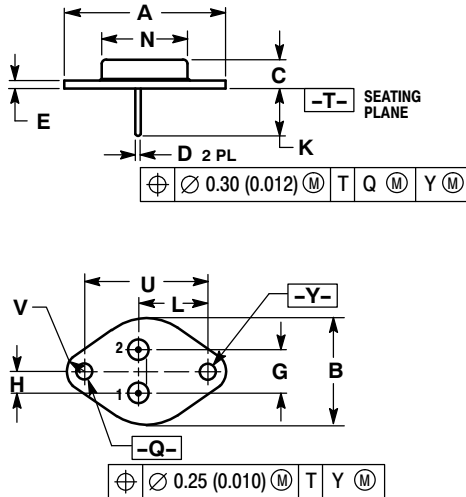


Figure 10. "On" Voltages

2N5684 (PNP), 2N5686 (NPN)

PACKAGE DIMENSIONS

TO-204 (TO-3)
CASE 197A-05
ISSUE K



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.530	REF	38.86	REF
B	0.990	1.050	25.15	26.67
C	0.250	0.335	6.35	8.51
D	0.057	0.063	1.45	1.60
E	0.060	0.070	1.53	1.77
G	0.430	BSC	10.92	BSC
H	0.215	BSC	5.46	BSC
K	0.440	0.480	11.18	12.19
L	0.665	BSC	16.89	BSC
N	0.760	0.830	19.31	21.08
Q	0.151	0.165	3.84	4.19
U	1.187	BSC	30.15	BSC
V	0.131	0.188	3.33	4.77

STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR

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